

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	- 30	V
V <sub>GS</sub>	Gate-Source Voltage	30	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units
		J174 -177	*MMBFJ175-177	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/∘C
R <sub>eJC</sub>	Thermal Resistance, Junction to Case	125		°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	556	°C/W

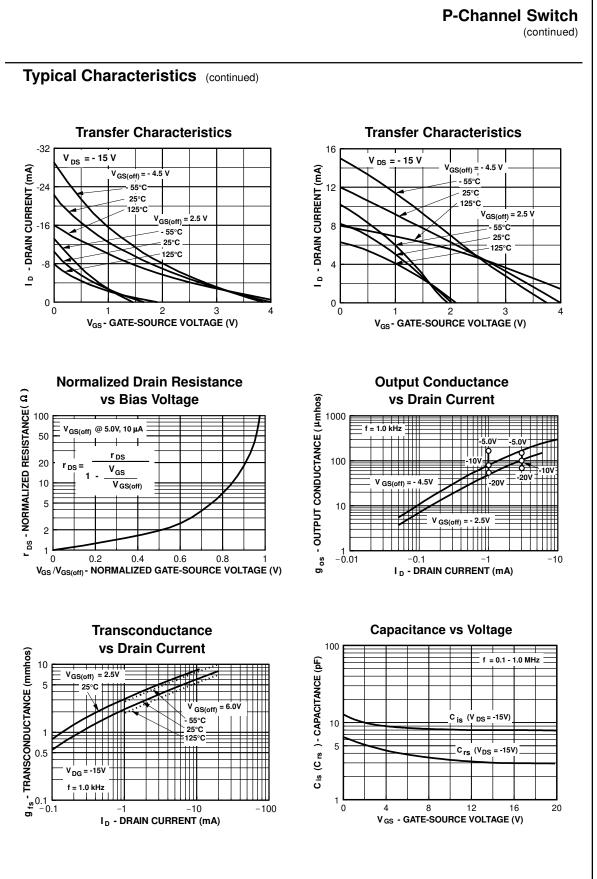
\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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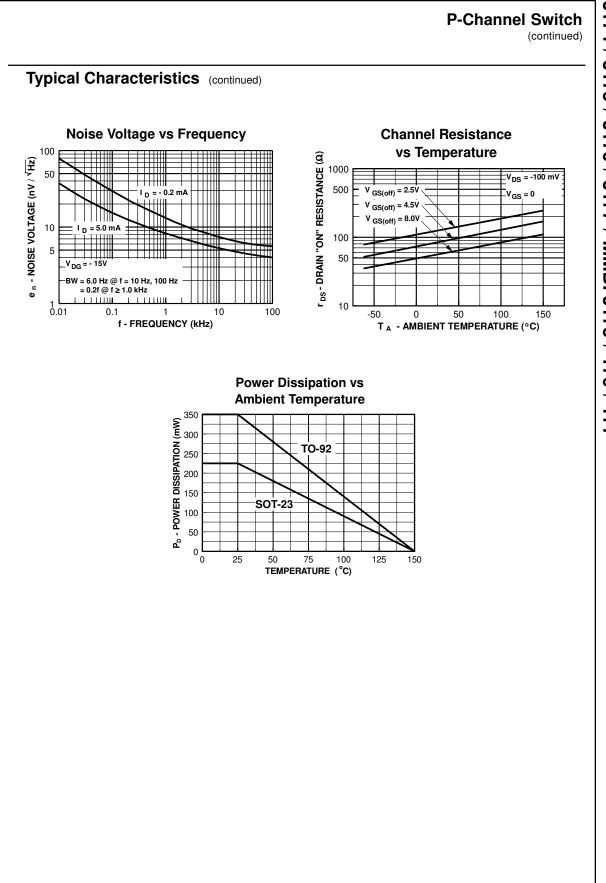
# P-Channel Switch (continued)

Symbol	Parameter	Test Conditions	;	Min	Max	Unit
B(BR)GSS	RACTERISTICS Gate-Source Breakdown Voltage	$I_G = 1.0 \ \mu A, \ V_{DS} = 0$		30		V
IGSS	Gate Reverse Current	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0$		50	1.0	nA
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	$V_{DS} = -15 V, I_D = -10 nA$	174	5.0	10	V
00(01)			175	3.0	6.0	V
			176 177	1.0 0.8	4.0 2.5	V V
	ACTERISTICS Zero-Gate Voltage Drain Current*		174	- 20	- 100	^
IDSS	Zero-Gale voltage Drain Current	$V_{DS} = -15 V, I_{GS} = 0$	174 175	- 7.0	- 60	mA mA
			176	- 2.0	- 25	mA
	Drain-Source On Resistance	$V_{DS} \le 0.1 \text{ V}, V_{GS} = 0$	<u>177</u> 174	- 1.5	- 20 85	mA
r <sub>DS(on)</sub>	Drain-Source On Resistance	$v_{DS} \leq 0.1 v, v_{GS} = 0$	174		125	Ω Ω
			176 177		250 300	Ω
Туріса	al Characteristics					
Туріса	al Characteristics Common Drain-Source	Param	eter Ir	Iteractio	ons	
-20	Common Drain-Source		eter Ir	iteractio		
-20	Common Drain-Source		eter Ir	iteractio		
-20	Common Drain-Source			- I <sub>DSS</sub>		
-20	Common Drain-Source			- I <sub>DSS</sub>		500
-20	Common Drain-Source			- I <sub>DSS</sub>	fs	100
-20	Common Drain-Source					500
-20	Common Drain-Source				9 15 = 15V,	500
I     - DRAIN CURRENT (m.d.)       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -       P     -	Common Drain-Source				9 15 = 15V,	500
-20	Common Drain-Source	g - TRANSCONDUCTANCE (mmhos)		1055 1055	5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	500 100 50
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<b>1 D A D R A I D A D R A I D A D I D C D R A I D C D R A I D D A I D D D D D D D D D D</b>	Common Drain-Source	g - TRANSCONDUCTANCE (mmhos)		1055 1055	5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	500 500 500 500 500 500 500 500 500 500
<b>1 D A D R A I D A D R A I D A D I D C D R A I D C D R A I D D A I D D D D D D D D D D</b>	Common Drain-Source	g - TRANSCONDUCTANCE (mmhos)		1055 1055	5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	500 500 500 500 500 500 500 500 500 500
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<b>1 D A D R A I D A D R A I D A D I D C D R A I D C D R A I D D A I D D D D D D D D D D</b>	Common Drain-Source	g - TRANSCONDUCTANCE (mmhos)		1055 1055	5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	500 500 500 500 500 500 500 500 500 500

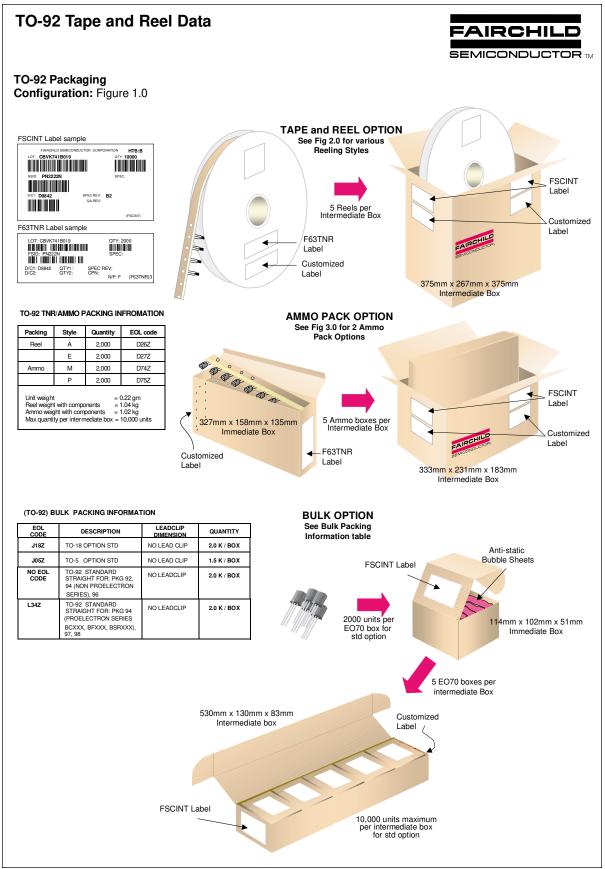
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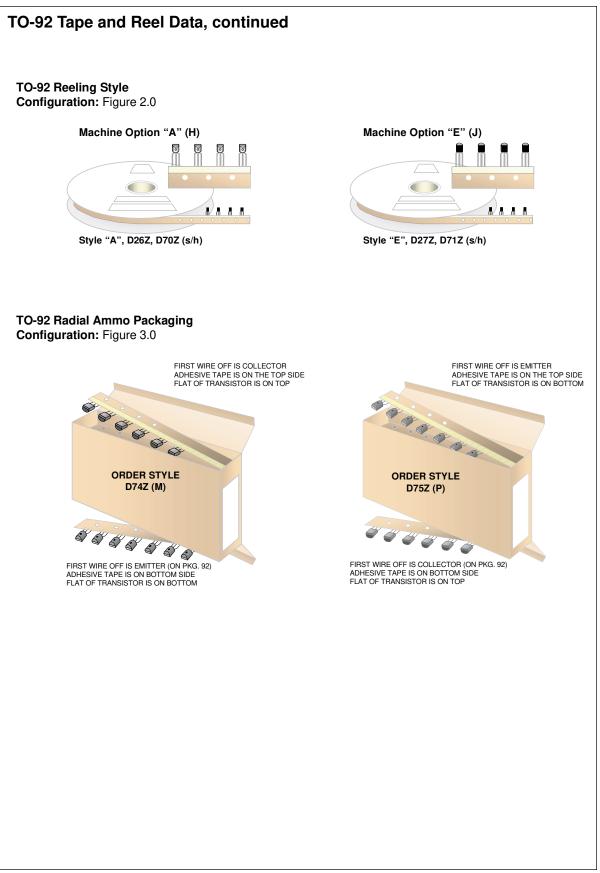


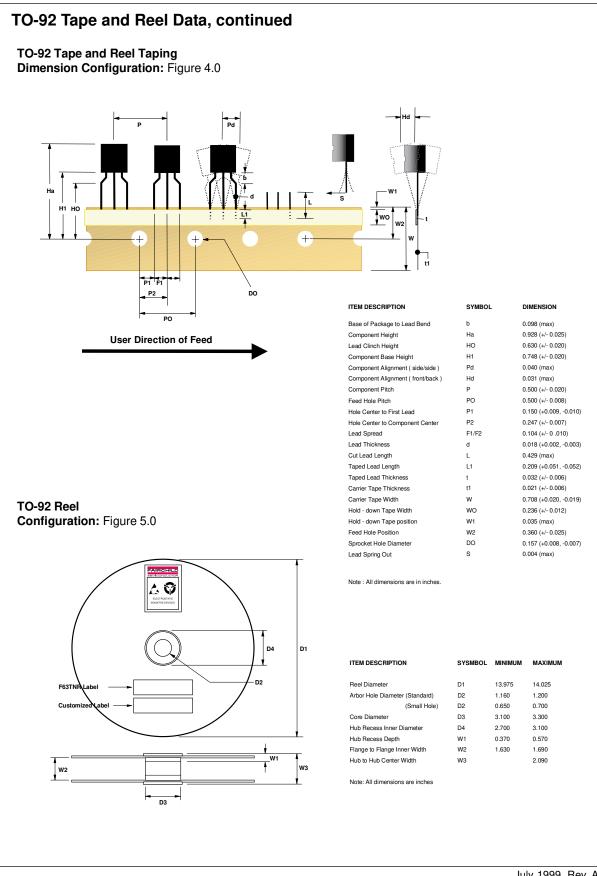
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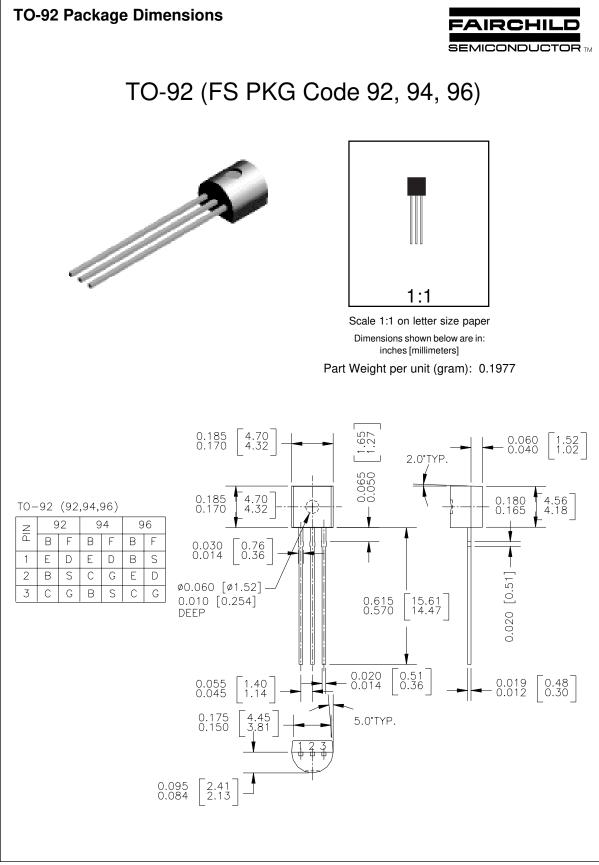


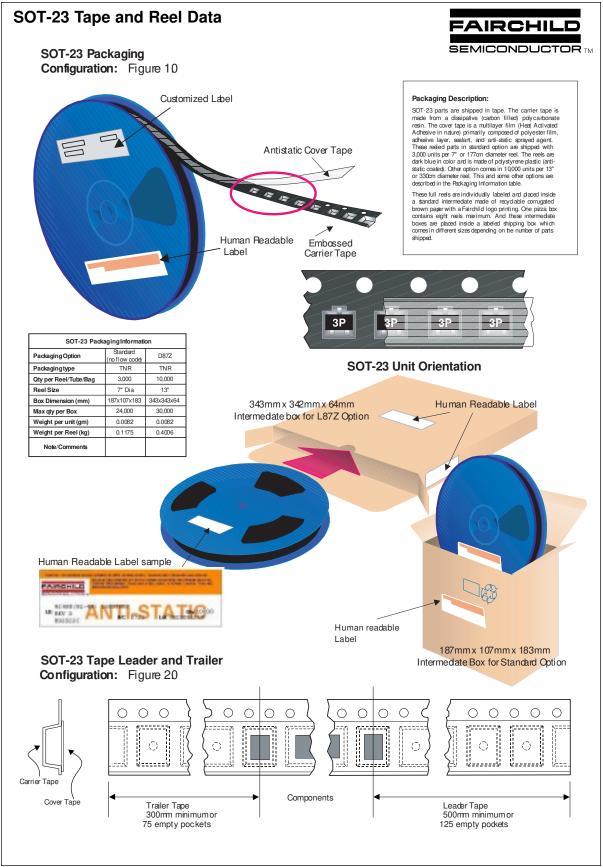
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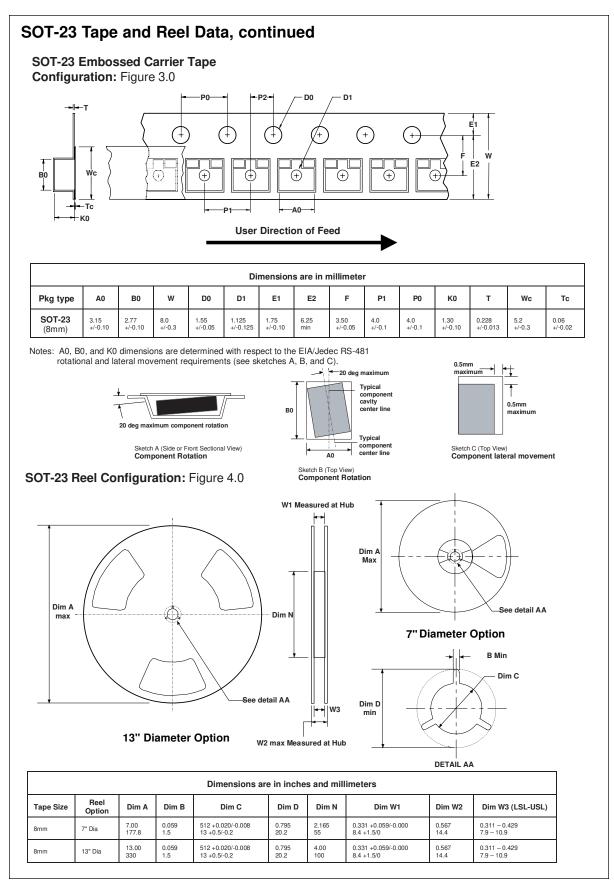




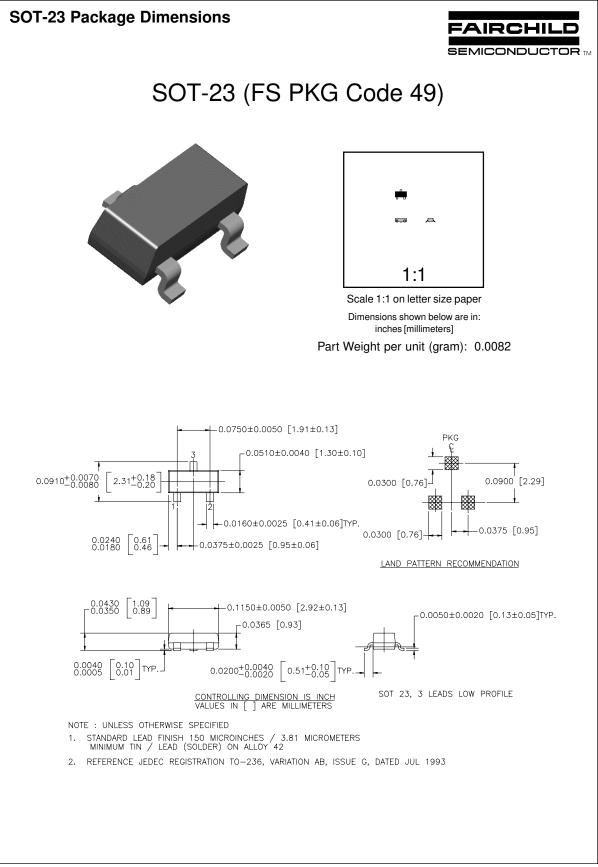


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